

## **Electronic Supplementary Information (ESI)**

# **Organic-Inorganic Hybrid Electron Transport Interlayer for High-Performance Inverted Polymer Solar Cells**

*Eui Jin Lee<sup>†</sup>, Soo Won Heo<sup>‡</sup>, Yong Woon Han<sup>†</sup> and Doo Kyung Moon<sup>†\*</sup>*

<sup>†</sup>Department of Materials Chemistry and Engineering, Konkuk University, 1 Hwayang-dong,  
Gwangjin-gu, Seoul 143-701, Republic of Korea

<sup>‡</sup> RIKEN Center for Emergent Matter Science (CEMS) 2-1 Hirosawa, Wako , Saitama 351-  
0198 , Japan

### **Corresponding Author**

\*E-mail : dkmoon@konkuk.ac.kr. Phone : +82 02 450 3498

## Contents

Fig. S1. X-ray diffraction patterns of ZnO and ZnO-PFN interlayers.

Fig. S2. AFM phase images (a) ZnO/PTB7:PCBM and (b) ZnO-PFN/PTB7:PCBM

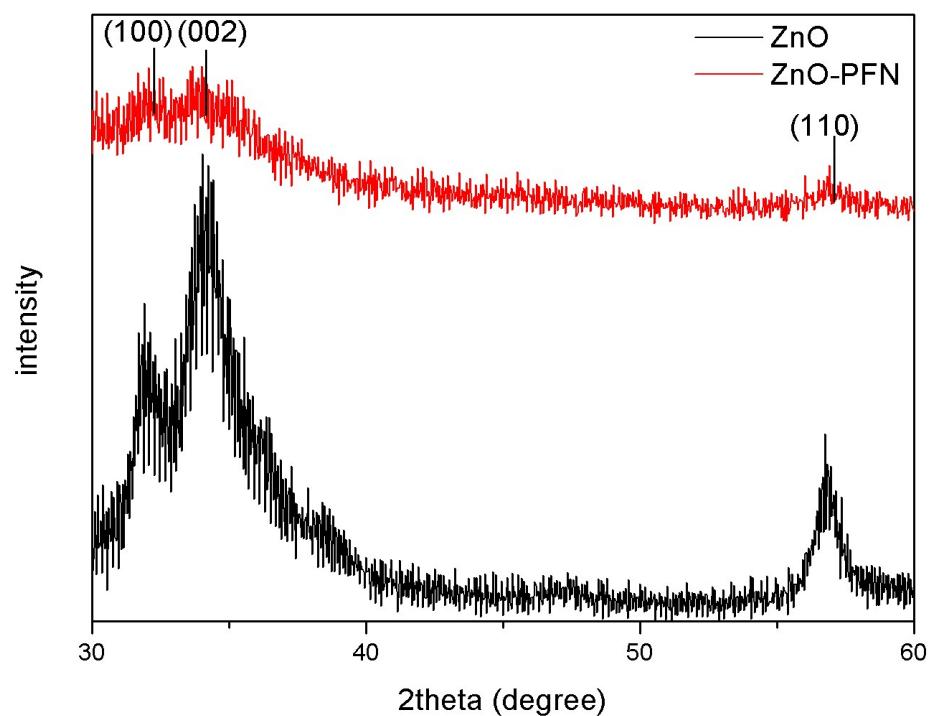
Fig. S3. *J-V* characteristics of the electron-only devices (a) ITO/ZnO or ZnO-PFN/Al, and (b) ITO/ZnO or ZnO-PFN/PTB7: PCBM /Al.

Fig. S4. Open circuit voltage ( $V_{oc}$ ), current density ( $J_{sc}$ ), fill factor (FF), power conversion efficiency (PCE) variation of 10 samples of ITO/ ZnO-PFN/PTB7: PCBM /MoO<sub>3</sub>/Ag.

Fig. S5. *J-V* characteristics of inverted devices with various PFN concentrations

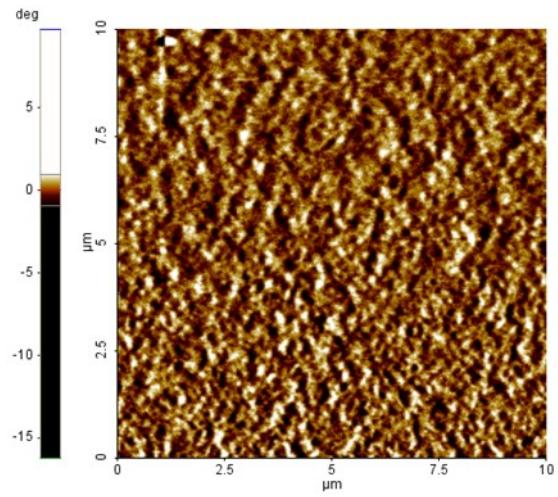
Table. S1. Electron mobility of the interlayers and photoactive layer determined using the electron-only devices ITO/ZnO or ZnO-PFN/Al and ITO/ZnO or ZnO-PFN/PTB7:PCBM/Al along with the use of space charge current equation in the calculation.

Table. S2. Photovoltaic performances of inverted PSCs with various PFN concentrations

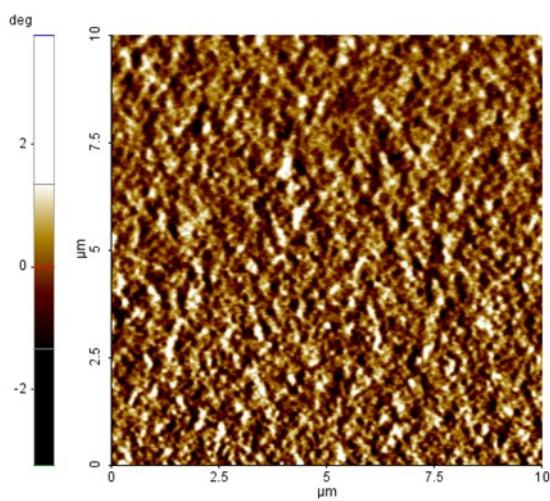


**Fig. S1** X-ray diffraction patterns of ZnO and ZnO-PFN interlayers.

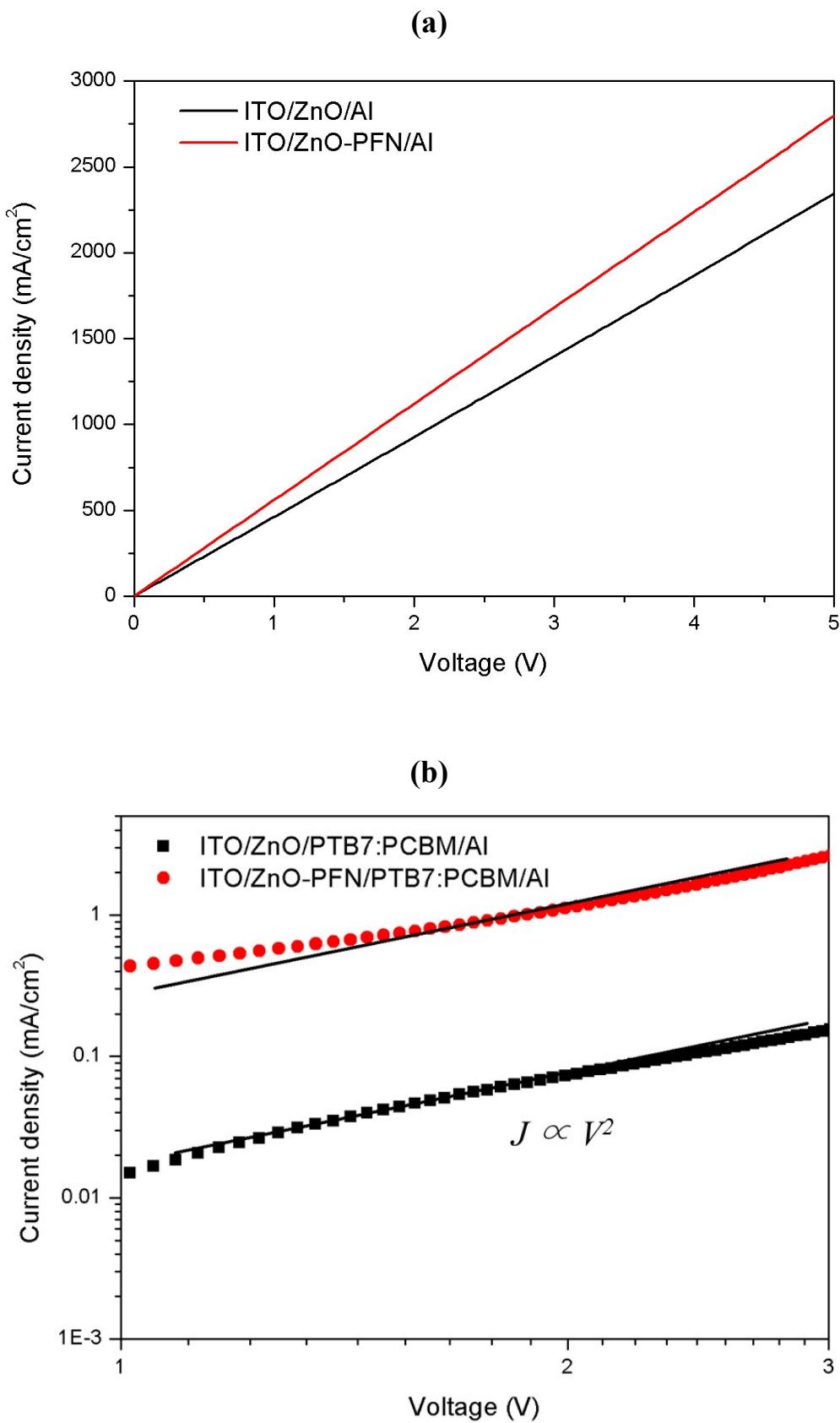
**(a)**



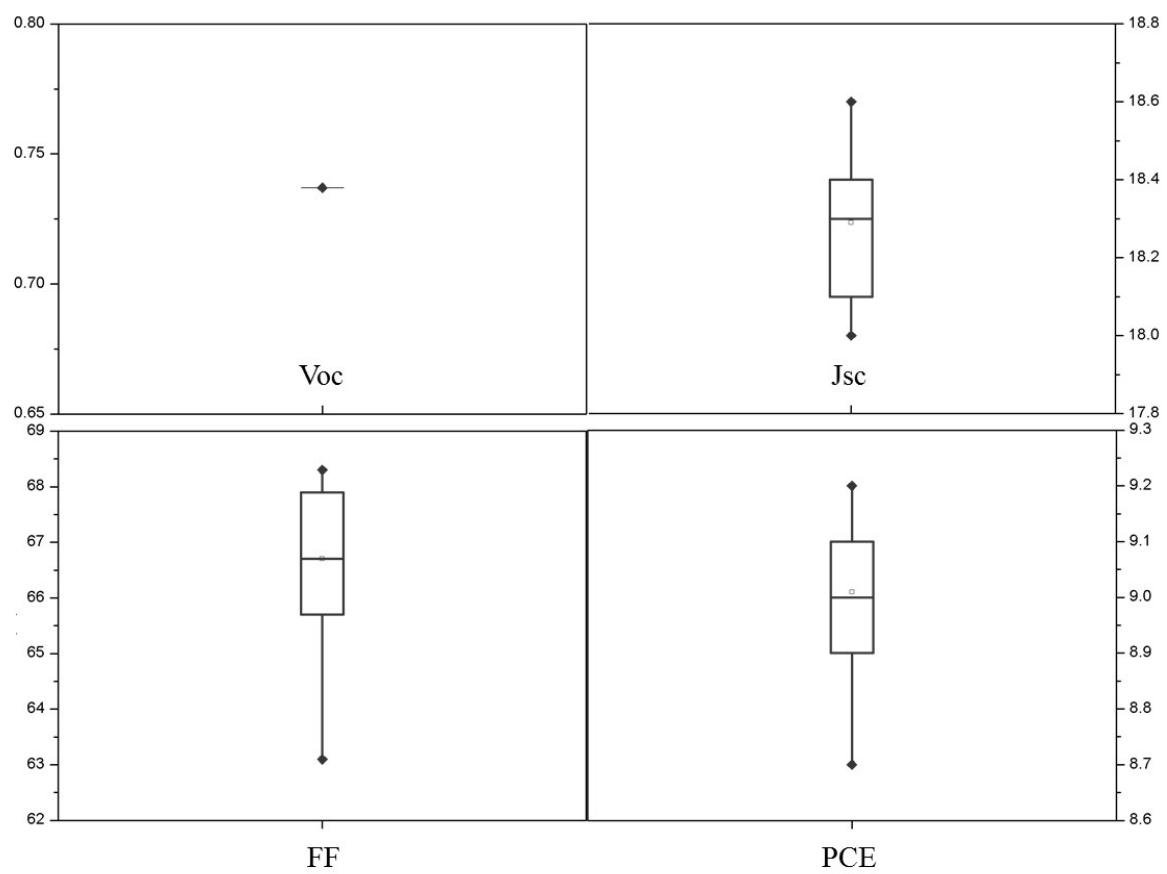
**(b)**



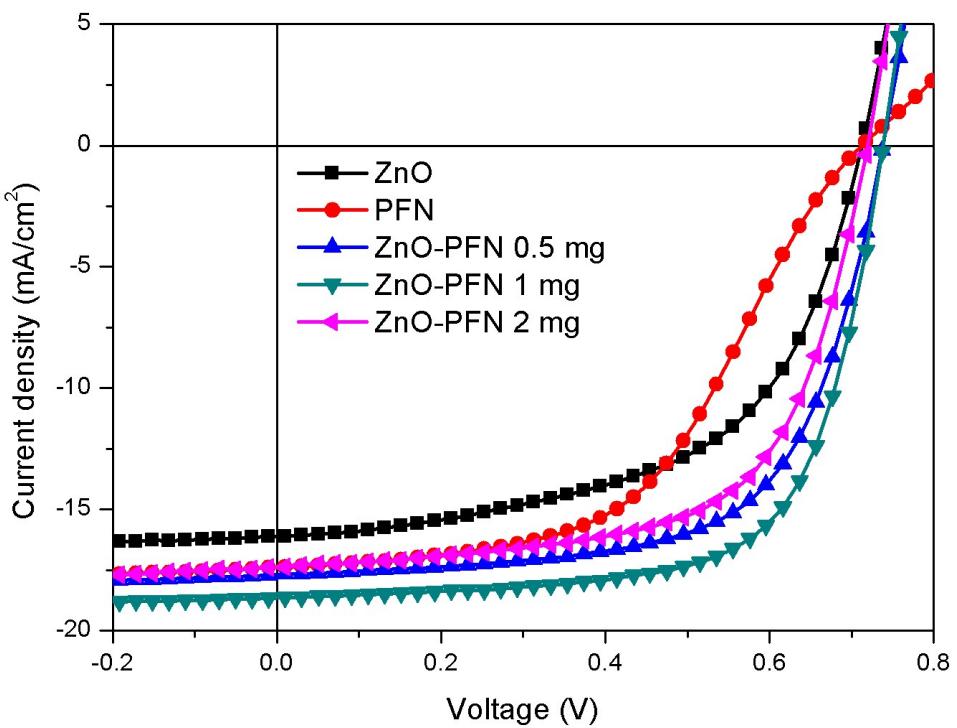
**Fig. S2.** AFM phase images (a) ZnO/PTB7:PCBM and (b) ZnO-PFN/PTB7:PCBM



**Fig. S3**  $J$ - $V$  characteristics of the electron-only devices (a) ITO/ZnO or ZnO-PFN/Al, and (b) ITO/ZnO or ZnO-PFN/PTB7: PCBM /Al.



**Fig. S4** Open circuit voltage (Voc), current density (Jsc), fill factor (FF), power conversion efficiency (PCE) variation of 10 samples of ITO/ZnO-PFN/PTB7:PCBM/MoO<sub>3</sub>/Ag.



**Fig. S5.**  $J$ - $V$  characteristics of inverted devices with various PFN concentrations

Table S1. Electron mobility of photoactive layer determined using the electron-only devices ITO/ZnO or ZnO-PFN/PTB7:PCBM/Al along with the use of space charge current equation in the calculation.

Devices	ITO/ZnO/	ITO/ZnO-PFN/
	PTB7:PCBM/Al	PTB7:PCBM/Al
$\mu_e$ [cm <sup>2</sup> /v·s]	1.71 x 10 <sup>-4</sup>	6.60 x 10 <sup>-4</sup>

Table. S2. Photovoltaic performances of inverted PSCs with various PFN concentrations

Cathode	PFN concentration	Jsc [mA/cm <sup>2</sup> ]	Voc [V]	FF [%]	PCE [%]
ITO/ZnO	-	16.3	0.717	61.7	7.2
ITO/PFN	2 mg/ml	17.4	0.717	50.5	6.3
ITO/ZnO-PFN	0.5 mg/ml	17.7	0.737	64.5	8.4
ITO/ZnO-PFN	1 mg/ml	18.3	0.737	67.8	9.2
ITO/ZnO-PFN	2 mg/ml	17.4	0.717	63.4	7.9